

Excellent Integrated System Limited

Stocking Distributor

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<u>Vishay Semiconductor/Diodes Division</u> <u>GL41T-E3/1</u>

For any questions, you can email us directly: sales@integrated-circuit.com

VISHAY

Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite Datasheet of GL41T-E3/1 - DIODE GEN PURP 1.3KV 1A DO213AB

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

BYM10-50 thru BYM10-1000, GL41A thru GL41Y



Vishay General Semiconductor

Surface Mount Glass Passivated Junction Rectifier

SUPERECTIFIER®



DO-213AB

PRIMARY CHARACTERISTICS								
I _F	F(AV)	1.0 A						
V	BYM-50-1000	50 V to 1000 V						
V_{RRM}	GL41A-Y	50 V to 1600 V						
l ₁	FSM	30 A						
	I _R	10 μA						
E	AS	5 mJ						
	V _F	1.1 V, 1.2 V						
TJ	max.	175 °C						

FEATURES

· Superectifier structure for high reliability condition



- Ideal for automated placement
- Low forward voltage drop
- Low leakage current
- High forward surge capability
- riigir forward dargo dapabiiity
- Meets environmental standard MIL-S-19500
- Meets MSL level 1, per J-STD-020, LF maximum peak of 250 °C
- AEC-Q101 qualified
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in general purpose rectification of power supplies, inverters, converters and freewheeling diodes for consumer, automotive and telecommunication.

MECHANICAL DATA

Case: DO-213AB, molded epoxy over glass body Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: Two bands indicate cathode end - 1st band denotes device type and 2nd band denotes repetitive peak reverse voltage rating

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)											
PARAMETER	SYMBOL	BYM 10-50	BYM 10-100	BYM 10-200	BYM 10-400	BYM 10-600	BYM 10-800	BYM 10-1000			UNIT
STANDARD RECOVERY DEVICE: 1 ST BAND IS WHITE		GL41A	GL41B	GL41D	GL41G	GL41J	GL41K	GL41M	GL41T	GL41Y	UNIT
Polarity color bands (2 nd band)		Gray	Red	Orange	Yellow	Green	Blue	Violet	White	Brown	
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	1300	1600	V
Maximum RMS voltage	V _{RMS}	35	70	140	280	420	560	700	910	1120	V
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	1000	1300	1600	V
Maximum average forward rectified current (fig. 1)	I _{F(AV)}		1.0						Α		
Peak forward surge current 8.3 ms single half sine-wave	I _{FSM}		30							Α	
Maximum full load reverse current full cycle average at T _A = 75 °C	I _{R(AV)}		30							μΑ	
Non-repetitive peak reverse avalanche energy at $T_J = 25$ °C, $I_{AS} = 1$ A, L = 10 mH	E _{AS}	5 -							mJ		
Operating junction and storage temperature range	T _J , T _{STG}				-	65 to + 1	75				°C

Revision: 30-Jan-13 1 Document Number: 88546



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)												
PARAMETER	TEST	SYMBOL	BYM 10-50	BYM 10-100	BYM 10-200	BYM 10-400	BYM 10-600	BYM 10-800	BYM 10-1000			UNIT
	CONDITIONS		GL41A	GL41B	GL41D	GL41G	GL41J	GL41K	GL41M	GL41T	GL41Y	
Maximum instantaneous forward voltage	1.0 A	V _F		1.1			1.2				V	
Maximum DC	T _A = 25 °C			10								
reverse current at rated DC blocking voltage	T _A = 125 °C	I _R		50							μA	
Typical junction capacitance	4.0 V, 1 MHz	CJ		8.0							pF	

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)											
PARAMETER	SYMBOL	BYM 10-50	BYM 10-100	BYM 10-200	BYM 10-400	BYM 10-600	BYM 10-800	BYM 10-1000			UNIT
		GL41A	GL41B	GL41D	GL41G	GL41J	GL41K	GL41M	GL41T	GL41Y	
Typical they mal vaciation as	R _{θJA} ⁽¹⁾		75								°C/W
Typical thermal resistance	R ₀ JT (2)			•	•	30			•	•	C/VV

Notes

 $^{^{(2)}}$ Thermal resistance from junction to terminal, 0.24" x 0.24" (6.0 mm x 6.0 mm) copper pads to each terminal

ORDERING INFORMATION (Example)									
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE					
BYM10-600-E3/96	0.114	96	1500	7" diameter plastic tape and reel					
BYM10-600-E3/97	0.114	97	5000	13" diameter plastic tape and reel					
GL41J-E3/96	0.114	96	1500	7" diameter plastic tape and reel					
GL41J-E3/97	0.114	97	5000	13" diameter plastic tape and reel					
BYM10-600HE3/96 (1)	0.114	96	1500	7" diameter plastic tape and reel					
BYM10-600HE3/97 (1)	0.114	97	5000	13" diameter plastic tape and reel					
GL41JHE3/96 (1)	0.114	96	1500	7" diameter plastic tape and reel					
GL41JHE3/97 (1)	0.114	97	5000	13" diameter plastic tape and reel					

Note

(1) AEC-Q101 qualified

 $^{^{(1)}}$ Thermal resistance from junction to ambient, 0.24" x 0.24" (6.0 mm x 6.0 mm) copper pads to each terminal

BYM10-50 thru BYM10-1000, GL41A thru GL41Y



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RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

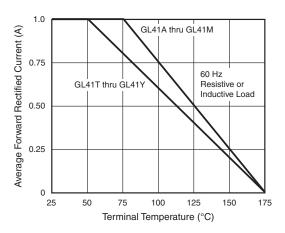


Fig. 1 - Forward Current Derating Curve

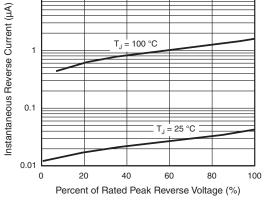


Fig. 4 - Maximum Non-Repetitive Peak Forward Surge Current

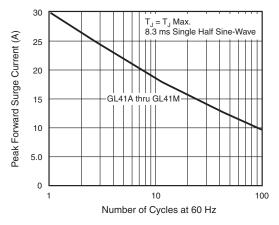


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

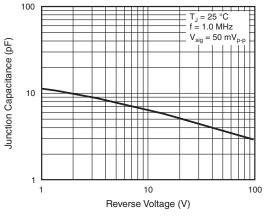


Fig. 5 - Typical Junction Capacitance

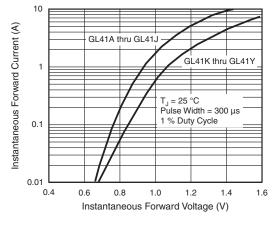


Fig. 3 - Typical Instantaneous Forward Characteristics

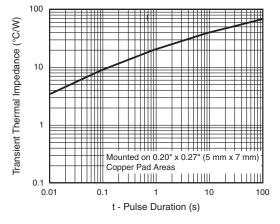


Fig. 6 - Typical Transient Thermal Impedance

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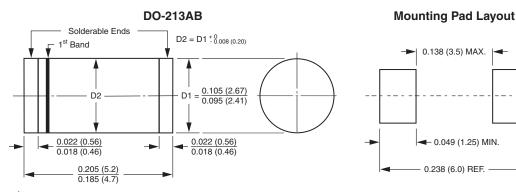


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0.118 (3.0) MIN.

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



1st band denotes type and positive end (cathode)



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